

DIMENSIONS

PIN NO. CONNECTION

(1)	D OUT
(2)	A OUT
(3)	NC
(4)	B OUT
(5)	C OUT
(6)	E OUT
(7)	GND
(8)	Vref
(9)	Vcc
(10)	F OUT

Chip position tolerance against PKG

$\Delta X = \pm 0.2\text{mm}$
 $\Delta Y = \pm 0.2\text{mm}$
 $\theta = \pm 0.2^\circ$

Pattern of the sensing area. (Unit: μm)

package center $0.6 \pm 0.2\text{mm}$

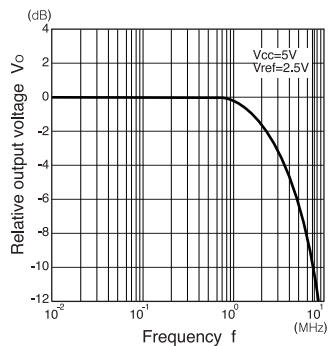
(Ta=25)

Item	Symbol	Rating	Unit
Supply voltage	V_{CC}	6	V
Power dissipation	P_o	100	mW
Operating temp.	Topr.	- 20 +80	
Storage temp.	Tstg.	- 30 +85	

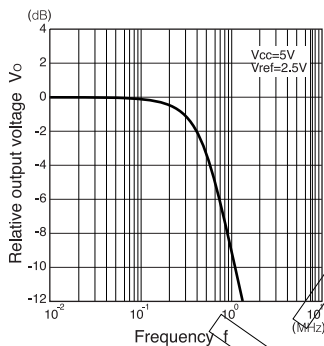
($V_{CC}=3V, V_{ref}=1.5V, R=10k\Omega, C_L=10k\Omega, T_a=25$)

Item	Symbol	Conditions	Min.	Typ.	Max.	Unit.
Current consumption	V_{CC}	(shading)		3	3.8	mA
Output offset voltage (A - F)	V_{off}	(shading)	- 15	0	15	mV
Output offset voltage difference (A - F)	ΔV_{off}	(A+B) - (C+D) (shading)	- 15	0	15	mV
		(A+D) - (B+C) (shading)	- 15	0	15	mV
		(A+C) - (B+D) (shading)	- 15	0	15	mV
		E - F (shading)	- 10	0	10	mV
Output voltage(A - D)	V_o	$P_o=10\mu W$ $\lambda=780nm$	290	370	450	mV
Output voltage(E,F)	V_o	$P_o=10\mu W$ $\lambda=780nm$	610	770	930	mV
Maximum output voltage(A - D)	V_{omax}	$P_o=100\mu W$ $\lambda=780nm$	2.0	2.2		V
Maximum output voltage(E,F)	V_{omax}	$P_o=100\mu W$ $\lambda=780nm$	2.5	2.9		V
Cutoff frequency(A - D)	f_c	100kHz- 3dB	2.5	3.0		MHz
Cutoff frequency(E,F)	f_c	10kHz- 3dB	100	400		KHz

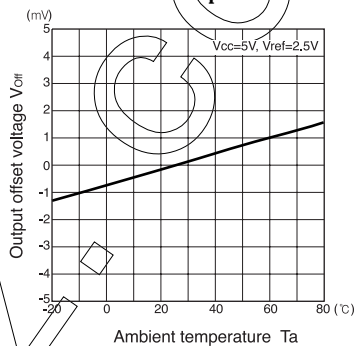
Focus



Tracking



Output offset voltage Vs. Ambient temperature



Relative output voltage Vs. Ambient temperature

